A	2022.4.28	ALL	AOS-AOD280A60		
B	2022.5.26	2,3,4,5	YC-RMX65R280SN_ReV1.1		

TO-252 N 650V

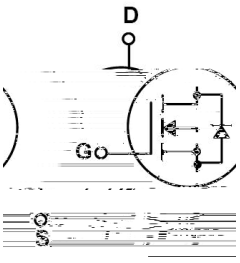
N-CHANNEL 650V Super-Junction Power MOSFET in a TO-252 Plastic Package.

$R_{DS(on)}$ C_{rss}

Low $R_{DS(on)}$,low gate charge, low C_{rss}, fast switching, HF Product.

DC/DC

Suited for low voltage applications such as automotive, DC/DC Converters, and high efficiency switching for power management in portable and battery operated products.

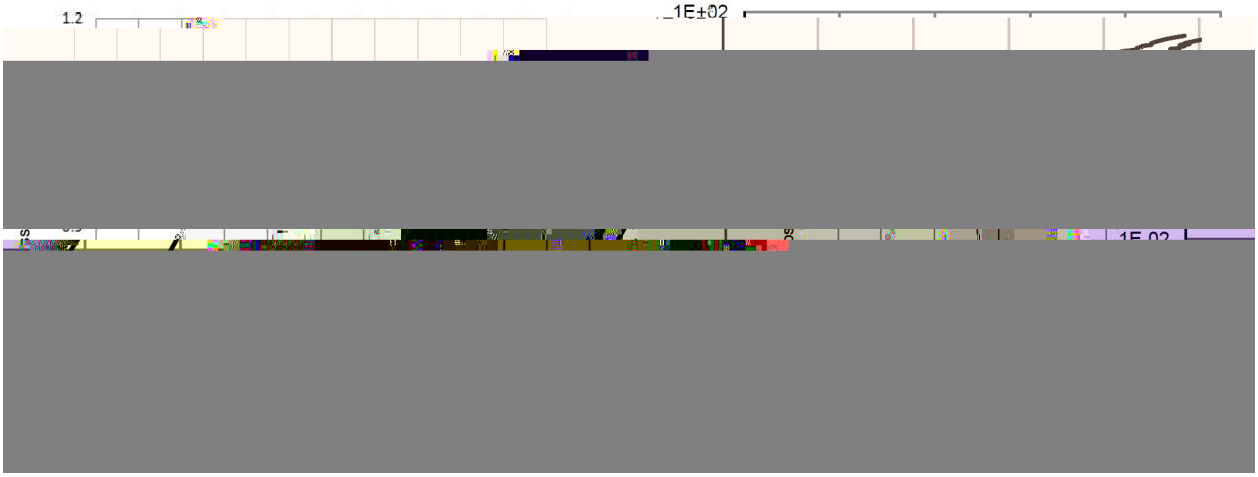


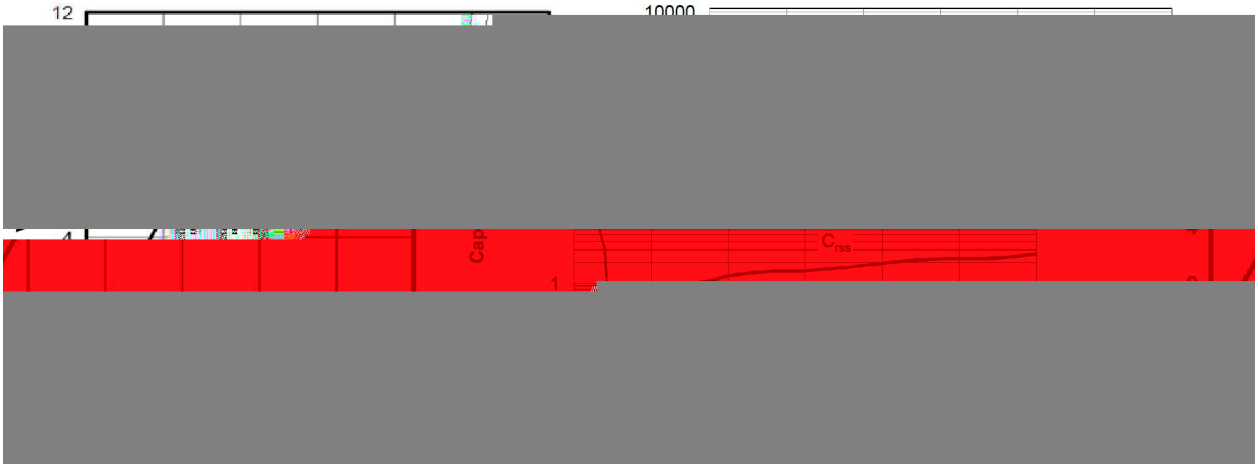
PIN1 G PIN 2 D PIN 3 S PIN 4 D

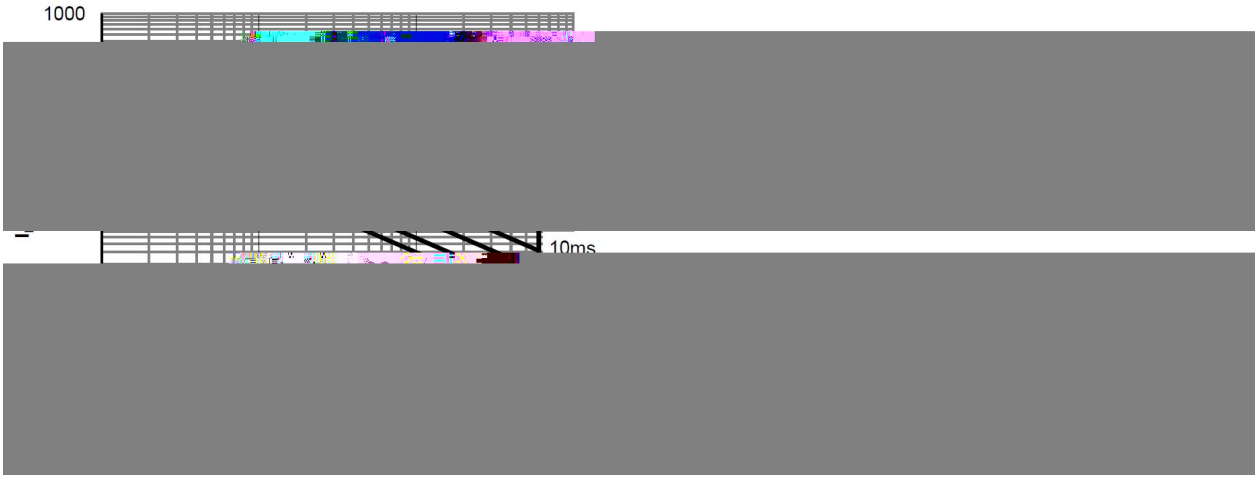
See Marking Instructions.

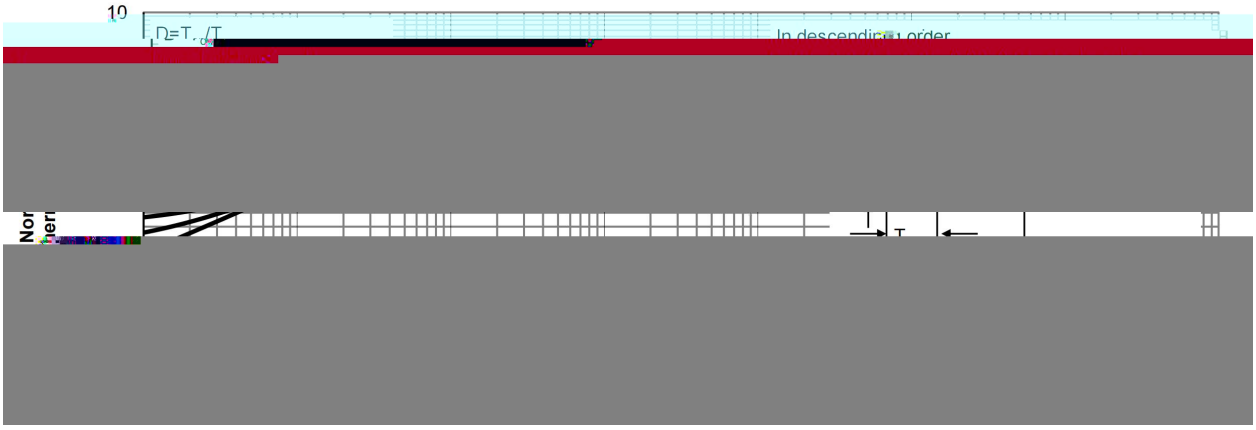
参数 Parameter	符号 Symbol	数值 Rating	单位 Unit
Drain-	V_{DS}	650	V

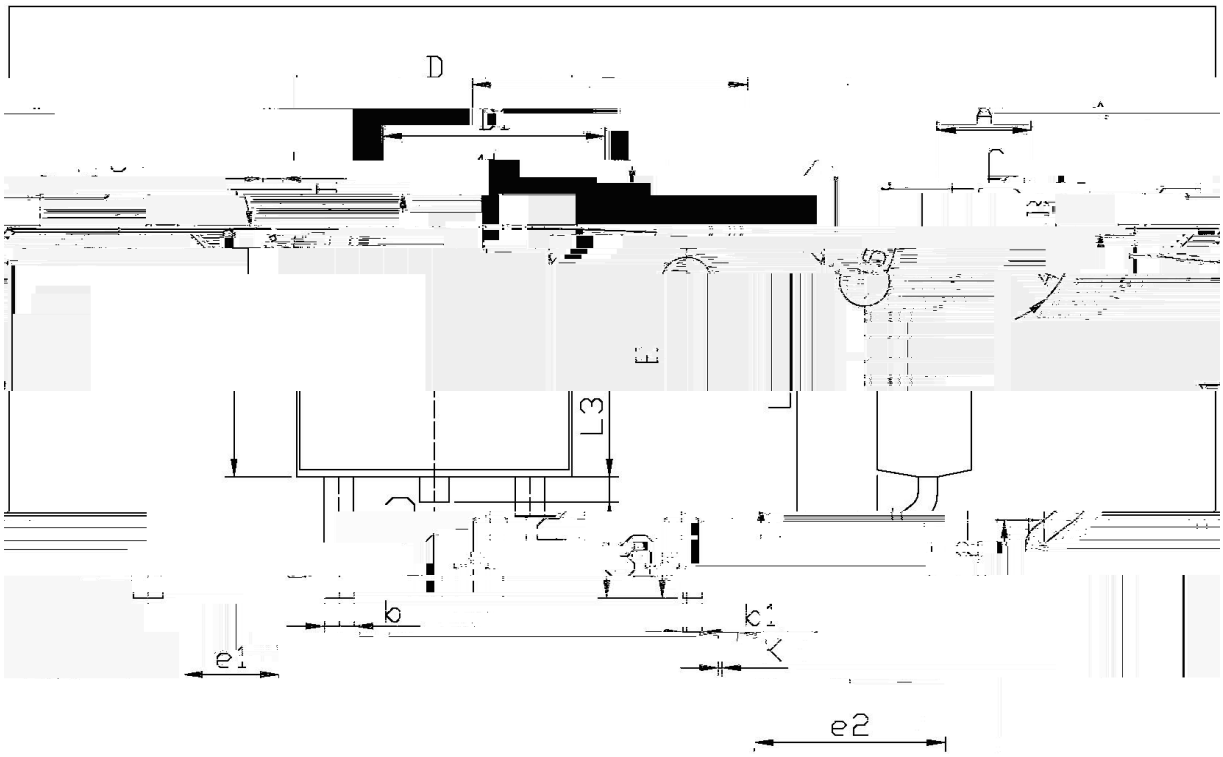
参数 Parameter	符号 Symbol	测试条件 Test Conditions	最小值 Min	典型值 Typ	最大值 Max	单位 Unit
Continuous Diode Forward Current	I_S				14	A
Total Gate Charge	Q_g	V_{DS}=520V I_D=7.5A V_{GS}=10V		26		nC
Gate-Source Charge	Q_{gs}			3.6		nC
Gate-Drain Charge	Q_{gd}			10.5		nC
Reverse recovery time	t_{rr}	V_R=400				

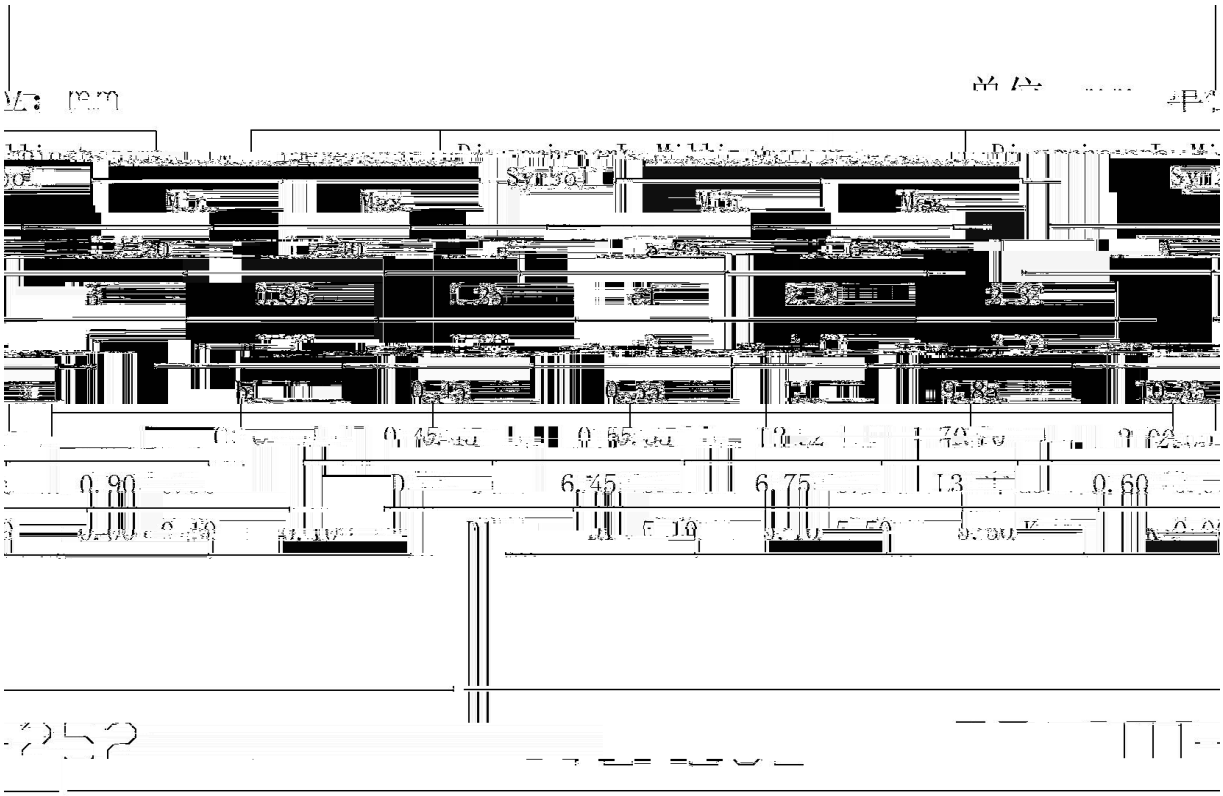


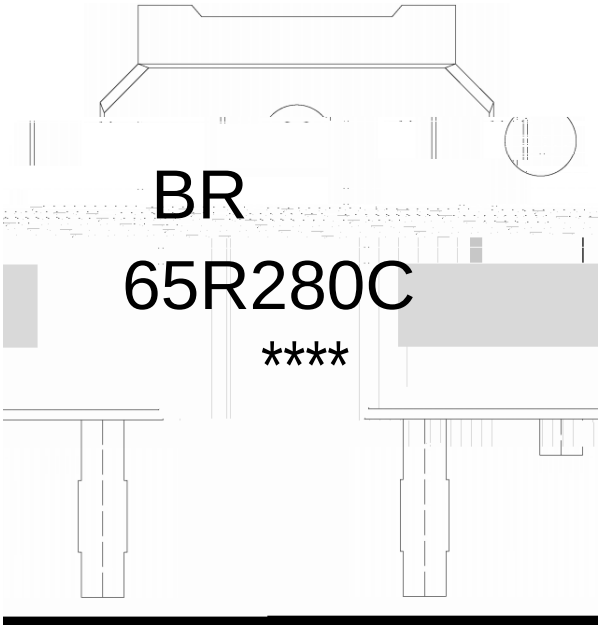

12
10000
Cap
C_{rss}
1


1000
10ms


10
D=T1/T2
In descending order
T


D
L3
b
b1
e1
e2


0.90
6.45
6.75
0.60



BR

Note:

BR:	Company Code
65R280C:	Product Type Code
****:	Lot No. Code, code change with Lot No

Note:

1	150	180	60	90sec;	1.Preh 50~180 , Time:60~90sec.
2	245±5			5±0.5sec;	2.Peak 245±5 , Duration:5±0.5sec.
3		2	10	/sec.	3. Cool d: 2~10 /sec.

260±5 10±1 sec. Temp.:26 Time:10±1 sec

/ REEL

Package Type 封装形式	Units 包装数量					nsion 包装尺寸 (unit: mm^3)	
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Inner Box 盒	Outer Box 箱
TO-252	2,500	2	5,000	6	30,000		

/ TUBE

Package Type 封装形式	Units 包装数量				
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	es/Outer Box 盒/箱	Units/Outer